## BRIEF COMMUNICATION

# Synthesis and Crystal Structure of a New Ruthenium Silicophosphate: $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ 

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A new ruthenium silicophosphate $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ was obtained and the structure was determined by single-crystal X-ray diffraction. It crystallizes in the trigonal space group $R \overline{3} c$ with $a=8.253(3) \AA, c=39.317(4) \AA, V=2319(2) \AA^{3}, Z=12, R=$ 0.029 , and $R_{W}=0.026$. The structure is composed of $\mathrm{RuO}_{6}$, $\mathrm{Si}_{2} \mathrm{O}_{7}$, and $\mathrm{P}_{2} \mathrm{O}_{7}$ units. The $\mathrm{Si}_{2} \mathrm{O}_{7}$ unit shares the six oxygen atoms with six $\mathrm{P}_{2} \mathrm{O}_{7}$ units, while the $\mathrm{P}_{2} \mathrm{O}_{7}$ unit shares the six oxygen atoms with two $\mathrm{Si}_{2} \mathrm{O}_{7}$ units and four $\mathrm{RuO}_{6}$ octahedra. The anionic part forms an infinite three-dimensional network of silicophosphate. $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ is isotypic with $\mathrm{MoP}_{3} \mathrm{SiO}_{11}$. © 1996 Academic Press, Inc.

Silicophosphates are the compounds having the condensed $\mathrm{SiO}_{4}$ and $\mathrm{PO}_{4}$ tetrahedra. These tetrahedra are further connected with metal polyhedra. Recently, many silicophosphates were discovered in the $M-\mathrm{P}-\mathrm{Si}-\mathrm{O}$ systems, $M=\mathrm{Cd}$ (1), V (2), Mo (3-7), Ti (8), Sn (8), Si (9), and Ge (10). In their structures, $\mathrm{PO}_{4}$ is connected with $X \mathrm{O}_{4}$ and $M \mathrm{O}_{6}$ (or $M_{2} \mathrm{O}_{9}$ ) units. On the other hand, $\mathrm{SiO}_{4}$ is connected only with $X_{O_{4}}$ tetrahedra.
In the present paper, we describe the preparation and structure of a new ruthenium silicophosphate $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$. It contains $\mathrm{Si}_{2} \mathrm{O}_{7}$ units with $D_{3 d}$ symmetry and $\mathrm{P}_{2} \mathrm{O}_{7}$ units. In the chemistry of phosphate, ruthenium has been less studied than in the case of molybdenum or other transition metals. Only two ruthenium phosphates have been reported (11), and $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ is the first silicophosphate of ruthenium.

Single crystals of $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ were accidentially obtained at first from a system containing niobium by the following method. The mixture of ruthenium chloride hydrate and $85 \%$ phosphoric acid in a mole ratio of $1: 3$ was heated at $350^{\circ} \mathrm{C}$ for 1 week under $\mathrm{N}_{2}$ gas, and a brown powder of an amorphous ruthenium phosphate $\mathrm{H}_{2} \mathrm{RuP}_{3} \mathrm{O}_{10}(11)$ was obtained. The powder precursor was mixed with $\mathrm{Nb}_{2} \mathrm{O}_{5}$
(metal ratio: $\mathrm{Nb} / \mathrm{Ru} \simeq 0.5$ ) and was sealed in a silica ampoule. The ampoule was heated at $950^{\circ} \mathrm{C}$ for 5 days and then slowly cooled at $5^{\circ} \mathrm{C} \cdot \mathrm{hr}^{-1}$ to $850^{\circ} \mathrm{C}$, and the furnace was turned off. Large yellow crystals of $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ were obtained as the main product. Though the crystals of $\mathrm{RuP}_{3^{-}}$ $\mathrm{SiO}_{11}$ have very good quality, they are mixed with a black powder of $\mathrm{Nb}_{2}\left(\mathrm{PO}_{4}\right)_{3}(12)$ and chemical analysis of the crystals was impossible.

Single crystals were obtained also from the system without niobium by the following procedure. The mixture of ruthenium chloride hydrate (Tanaka) and $85 \%$ phosphoric acid (Koso-kagaku) in a mole ratio of $1: 4$ was heated in air for 40 min , and the residue was then heated in platinum boats under $\mathrm{N}_{2}$ gas flow at $350^{\circ} \mathrm{C}$ for 1 week. The resulted brown powder was amorphous ruthenium phosphate ( Ru content $24.2 \%$ ). It was pressed into a pellet and sealed in an evacuated silica ampoule. The ampoule was heated at $950^{\circ} \mathrm{C}$ for 5 days, and yellow thin plate crystals of $\mathrm{RuP}_{3^{-}}$ $\mathrm{SiO}_{11}$ were obtained with a small amount of $\mathrm{RuO}_{2}$. Silicon in $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ comes from the silica ampoule. The crystals yielded in this reaction were very thin. Even the largest crystal, which was used for single-crystal X-ray study, was only $0.01-\mathrm{mm}$ thick.

The structures of the two crystals, one from the Ru-P-$\mathrm{Si}-\mathrm{O}$ system and another from the $\mathrm{Ru}-\mathrm{Nb}-\mathrm{Si}-\mathrm{P}-\mathrm{O}$ system, have been determined by single-crystal X-ray studies. Atomic parameters were determined by the Patterson method (SHELXS86 (13)) and Fourier techniques (SHELXS76 (14)). A full-matrix least-squares program ANYBLK (15) was used for the final refinement. The crystallographic and experimental data of the two crystals are summarized in Table 1. The comparison of the results shows that they are the same compound. The cell parameters of the two crystals are identical within the normal experimental error. The refined atomic coordinates of the two crystals have only the statistically expected differences, i.e., the maximum value of $\Delta /\left(\sigma_{1}^{2}+\sigma_{2}^{2}\right)^{1 / 2}$ was 2.2 . Here,

TABLE 1
Crystallographic Data for $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$

|  | Crystal $1^{a}$ | Crystal $2^{\text {a }}$ |
| :---: | :---: | :---: |
| Formula weight | 398.07 | 398.07 |
| Space group | $R \overline{3} c$ (No. 167) | $R \overline{3} c$ (No. 167) |
| $a(\AA)$ | 8.247(2) ${ }^{\text {b }}$ | 8.253(3) ${ }^{\text {b }}$ |
| $c(\AA)$ | 39.287(4) ${ }^{\text {b }}$ | 39.317(4) ${ }^{\text {b }}$ |
| $V\left(\AA^{3}\right)$ | 2314(1) | 2319(2) |
| Z | 12 | 12 |
| $F(000)$, electrons | 3348 | 3348 |
| $D_{\text {calcd }}\left(\mathrm{g} \cdot \mathrm{cm}^{-3}\right)$ | 3.428 | 3.421 |
| $T(\mathrm{~K})$ of data collection | 296 | 296 |
| Crystal size (mm) | $0.12 \times 0.10 \times 0.01$ | $0.25 \times 0.12 \times 0.05$ |
| Diffratometer | Rigaku AFC-5R | Rigaku AFC-6S |
| Radiation (graphite monochromated) | MoK $0.7107 \AA$ | MoK $0.7107 \AA{ }^{\text {a }}$ |
| Scan mode | $2 \theta-\omega$ | $2 \theta-\omega$ |
| Scan range (degree) | $1.10+0.3 \tan \omega$ | $1.26+0.3 \tan \omega$ |
| Collection region | $\begin{aligned} & 0 \leq h \leq 12 \\ & -12 \leq k \leq 12 \\ & -55 \leq l \leq 55 \end{aligned}$ | $\begin{aligned} & 0 \leq h \leq 9 \\ & -10 \leq k \leq 10 \\ & 0 \leq l \leq 54 \end{aligned}$ |
| $2 \theta$ limit | $5^{\circ} \leq 2 \theta \leq 60^{\circ}$ | $5^{\circ} \leq 2 \theta \leq 60^{\circ}$ |
| No. of measured reflections | 4821 | 2448 |
| No. of unique reflections | 908 | 767 |
| No. of observed reflections | 520 | 611 |
|  | $\left\|F_{\mathrm{o}}\right\|>4 \sigma\left(\left\|F_{\mathrm{o}}\right\|\right)$ | $\left\|F_{\mathrm{o}}\right\|>3 \sigma\left(\left\|F_{\mathrm{o}}\right\|\right)$ |
| Linear absorption coeff. $\mu\left(\mathrm{cm}^{-1}\right)$ | 28.71 | 28.65 |
| Absorption correction | $\psi$-scan correct with -6 1-10 reflection | $\begin{aligned} & \psi \text {-scan correct with } \\ & -150 \\ & \text { reflection } \end{aligned}$ |
| Transmission factor | 0.7738/0.9725 | 0.7846/0.9880 |
| No. of variable parameters weighting scheme | $\begin{aligned} & 50 \\ & w=1 / \sigma^{2}\left(\left\|F_{\mathrm{o}}\right\|\right) \end{aligned}$ | $\begin{aligned} & 50 \\ & w=1 / \sigma^{2}\left(\left\|F_{\mathrm{o}}\right\|\right) \end{aligned}$ |
| $R, R_{w}^{c}$ | $0.0367,0.0233$ | 0.0290, 0.0260 |
| Goodness of fit, $S^{d}$ | 1.50 | 2.07 |
| Residual density ${ }^{e} \AA^{-3}$ | 1.04 | 0.87 |

[^0]TABLE 3
Bond Distances and Angles in $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$

| Ru | O 2 | $\mathrm{O}^{\# 1}$ | $\mathrm{O} 2^{\# 2}$ | O 3 | $\mathrm{O}^{\# 1}$ | $\mathrm{O}^{\# 2}$ |
| :--- | ---: | ---: | ---: | ---: | ---: | ---: |
| O2 | $\mathbf{2 . 0 4 0 ( 3 )}$ | $2.792(5)$ | $2.792(5)$ | $2.967(4)$ | $4.085(4)$ | $2.920(4)$ |
| O2 $^{\# 1}$ | $86.36(12)$ | $\mathbf{2 . 0 4 0 ( 3 )}$ | $2.792(5)$ | $2.920(4)$ | $2.967(4)$ | $4.085(4)$ |
| O2 $^{\# 2}$ | $86.36(12)$ | $86.36(12)$ | $\mathbf{2 . 0 4 0 ( 3 )}$ | $4.085(4)$ | $2.920(4)$ | $2.967(4)$ |
| O3 $^{\# 1}$ | $93.15(12)$ | $91.21(12)$ | $177.55(12)$ | $\mathbf{2 . 0 4 6 ( 3 )}$ | $2.874(5)$ | $2.874(5)$ |
| O3 $^{\# 1}$ | $177.55(12)$ | $93.15(12)$ | $91.21(12)$ | $89.26(12)$ | $\mathbf{2 . 0 4 6 ( 3 )}$ | $2.874(5)$ |
| O3 $^{\# 2}$ | $91.21(12)$ | $177.55(12)$ | $93.15(12)$ | $89.26(12)$ | $89.26(12)$ | $\mathbf{2 . 0 4 6 ( 3 )}$ |


| Si | O1 | $\mathrm{O} 1^{\# 1}$ | $\mathrm{O} 1^{\# 2}$ | O5 |
| :---: | :---: | :---: | :---: | :---: |
| O1 | 1.608(3) | $2.634(5)$ | $2.634(5)$ | 2.588(3) |
| O1 ${ }^{\text {\#1 }}$ | 109.96(12) | 1.608(3) | $2.634(5)$ | 2.588(3) |
| O1*2 | 109.96(12) | 109.96(12) | 1.608(3) | 2.588(3) |
| O5 | 108.97(12) | 108.97(12) | 108.97(12) | 1.571(2) |
| P | O1*5 | O2 | $\mathrm{O3}^{\# 4}$ | $\mathrm{O} 4{ }^{\# 3}$ |
| O1*5 | 1.581(3) | 2.527(4) | 2.494(4) | 2.462(5) |
| O2 | 111.3(2) | 1.479(3) | $2.559(4)$ | 2.479(4) |
| O3 ${ }^{\# 4}$ | 108.3(2) | 118.8(2) | 1.494(3) | 2.495 (3) |
| O4 ${ }^{\# 3}$ | 101.7(2) | 107.52(14) | 107.8(2) | 1.594(2) |

$$
\begin{aligned}
& \text { \#1: }-y, x-y, z ; \text { " }^{\# 2}:-x+y,-x, z ;{ }^{\# 3}:-x+y+2 / 3,-x+1 / 3, z+1 / 3 \\
& { }^{\# 4}:-x+2 / 3,-y+1 / 3,-z+1 / 3 ;{ }^{55}:-x+1 / 3,-x+y+2 / 3,-z+1 / 6
\end{aligned}
$$

angle $(\mathrm{P}-\mathrm{O} 1-\mathrm{Si})=134.7(2)^{\circ}$
angle $(\mathrm{P}-\mathrm{O} 4-\mathrm{P})=127.9(3)^{\circ}$
angle $(\mathrm{Si}-\mathrm{O} 5-\mathrm{Si})=180^{\circ}$
$\Delta$ is the difference of the corresponding atomic parameters, and $\sigma_{1}$ and $\sigma_{2}$ are the estimated standard deviations of them. Because the results of the crystal obtained from the $\mathrm{Ru}-\mathrm{Nb}-\mathrm{Si}-\mathrm{P}-\mathrm{O}$ system have better accuracy, we give them in Tables 2 and 3.

The structure of $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ has a three-dimensional network of silicophosphate ion composed of $\mathrm{Si}_{2} \mathrm{O}_{7}$ and $\mathrm{P}_{2} \mathrm{O}_{7}$ subunits (Fig. 1). $\mathrm{A}_{\mathrm{Si}_{2} \mathrm{O}_{7} \text { fragment is illustrated at the }}$ center of Fig. 1. The bond lengths and angles are $\mathrm{Si}-$

TABLE 2
Atomic Parameters for $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ with Standard Deviations in Parentheses

| Atom | $x$ | $y$ | $z$ | $U\left(\AA^{2}\right)$ | $U_{11}{ }^{a}$ | $U_{22}{ }^{a}$ | $U_{33}{ }^{a}$ | $U_{12}{ }^{a}$ | $U_{13}{ }^{a}$ | $U_{23}{ }^{a}$ |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| Ru | 0.0 | 0.0 | $0.158752(14)$ | $0.0050(2)$ | $0.56(2)$ | $0.56(2)$ | $0.40(2)$ | $0.278(8)$ | 0.0 | 0.0 |
| P | $0.3715(2)$ | $0.0393(2)$ | $0.11974(3)$ | $0.0062(4)$ | $0.63(5)$ | $0.66(5)$ | $0.55(5)$ | $0.31(4)$ | $-0.01(5)$ | $-0.04(5)$ |
| Si | 0.0 | 0.0 | $0.03997(5)$ | $0.0059(6)$ | $0.66(5)$ | $0.66(5)$ | $0.46(9)$ | $0.33(3)$ | 0.0 | 0.0 |
| O1 | $0.0477(5)$ | $0.2035(4)$ | $0.05327(8)$ | $0.0082(13)$ | $1.1(2)$ | $0.6(2)$ | $1.0(2)$ | $0.60(13)$ | $-0.22(13)$ | $-0.06(12)$ |
| O 2 | $0.2235(4)$ | $0.0858(4)$ | $0.12695(7)$ | $0.0089(14)$ | $0.80(15)$ | $1.0(2)$ | $0.93(15)$ | $0.49(13)$ | $0.54(12)$ | $0.38(13)$ |
| O3 | $0.1361(5)$ | $0.2309(4)$ | $0.18918(7)$ | $0.0101(13)$ | $1.0(2)$ | $0.9(2)$ | $1.1(2)$ | $0.51(14)$ | $-0.36(13)$ | $-0.47(12)$ |
| O4 | $0.2098(5)$ | 0.0 | 0.75 | $0.008(2)$ | $0.9(2)$ | $1.3(2)$ | $0.5(2)$ | $0.64(12)$ | $0.14(9)$ | $0.3(2)$ |
| O5 | 0.0 | 0.0 | 0.0 | $0.014(3)$ | $1.7(2)$ | $1.7(2)$ | $0.8(4)$ | $0.87(12)$ | 0.0 | 0.0 |

[^1]

FIG. 1. A partial structure of the silicophosphate ion in $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$. Shaded polyhedra are $\mathrm{Si}_{2} \mathrm{O}_{7}$ units and open polyhedra are $\mathrm{P}_{2} \mathrm{O}_{7}$ units.
$\mathrm{O}_{\text {terminal }}=1.61 \AA, \mathrm{Si}-\mathrm{O}_{\text {bridge }}=1.57 \AA$, and angle $(\mathrm{Si}-\mathrm{O}-$ $\mathrm{Si})=180^{\circ}$. Six terminal oxygen atoms of $\mathrm{Si}_{2} \mathrm{O}_{7}$ are bonded to the surrounding six $\mathrm{P}_{2} \mathrm{O}_{7}$ subunits. The $\mathrm{P}-\mathrm{O}$ bond lengths in the $\mathrm{P}_{2} \mathrm{O}_{7}$ groups are $1.58 \AA$ (with O atoms connected with Si atoms), $1.48 \AA$ (with O atoms connected with Ru atoms), and $1.59 \AA$ (with a bridging O atom). The $\mathrm{PO}_{4}$ tetrahedra are smaller than the $\mathrm{SiO}_{4}$ tetrahedra, and this is always observed in silicophosphates.
The six $\mathrm{P}_{2} \mathrm{O}_{7}$ units in Fig. 1 are bonded with other $\mathrm{Si}_{2} \mathrm{O}_{7}$ to form an infinite network. Figure 2(a) illustrates the projection of four unit cells of $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ on the $a-b$ plane. Shaded polyhedra indicate $\mathrm{SiO}_{4}$. Each $\mathrm{PO}_{4}$ unit is connected to one $\mathrm{SiO}_{4}$ and two $\mathrm{RuO}_{6}$ (dotted polyhedra) through three terminal oxygen atoms. Ruthenium atoms exist on threefold axes, and are bonded with the two kinds of oxygen atoms. However, the interatomic distances of $\mathrm{Ru}-\mathrm{O}$ are 2.04 and $2.05 \AA$, and the $\mathrm{RuO}_{6}$ octahedron is almost regular. These distances are similar to those observed in $\mathrm{Ru}^{\mathrm{III}} \mathrm{P}_{3} \mathrm{O}_{9}$ polymorphs ( $2.00 \sim 2.06 \AA$ ) (11).

Figure 2(b) shows the projection of $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ along the (1 1100 ) direction. The crystal structure is constructed from six identical layers as indicated in Fig. 2(b). The layers are built up of $\mathrm{RuO}_{6}, \mathrm{Si}_{2} \mathrm{O}_{7}$, and $\mathrm{PO}_{4}$ units and are stacked along the $c$ axis sharing the apices of the $\mathrm{PO}_{4}$ tetrahedra. The layer is observed in many silicophosphates such as $A \mathrm{Mo}_{3} \mathrm{P}_{6} \mathrm{Si}_{2} \mathrm{O}_{25}(A=\mathrm{Rb}, \mathrm{Cs}$, and Tl$)(3,4), \mathrm{Si}_{5} \mathrm{P}_{6} \mathrm{O}_{25}(9)$, and


FIG. 2. (a) The structure of $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ projected on the $a-b$ plane. Four unit cells are seen in this figure. Dotted polyhedra are $\mathrm{RuO}_{6}$ and shaded polyhedra are $\mathrm{Si}_{2} \mathrm{O}_{7}$. Open tetrahedra are $\mathrm{PO}_{4}$ units. For the simplification, the figure shows one independent layered substructure (see (b)). (b) The unit cell of $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ projected along the ( $\left.\begin{array}{lll}1 & 1 & 0\end{array}\right)$ direction. It is constructed of six identical layers. The layers are connected with the oxygen atoms of pyrophosphate units.
$\mathrm{MoP}_{3} \mathrm{SiO}_{11}(5)$. While the layers of $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$ and $\mathrm{MoP}_{3}{ }^{-}$ $\mathrm{SiO}_{11}$ are directly connected with each other, those of $A \mathrm{Mo}_{3} \mathrm{P}_{6} \mathrm{Si}_{2} \mathrm{O}_{25}$ and $\mathrm{Si}_{5} \mathrm{P}_{6} \mathrm{O}_{25}$ are connected through another $\mathrm{MO}_{6}$ monolayer.

The structure of $\mathrm{MoP}_{3} \mathrm{SiO}_{11}$ was described in the monoclinic space group $C 2 / c$. However, the reported monoclinic unit cell can be converted into a new unit cell with $a=$ $8.419 \AA, b=8.419 \AA, c=39.962 \AA, \alpha=90.00^{\circ}, \beta=90.00^{\circ}$, and $\gamma=120.02^{\circ}$. Here, the cell vectors of the new unit cell are defined by $\boldsymbol{a}=1 / 2\left(\boldsymbol{a}_{\mathrm{m}}+\boldsymbol{b}_{\mathrm{m}}\right), \boldsymbol{b}=1 / 2\left(-\boldsymbol{a}_{\mathrm{m}}+\boldsymbol{b}_{\mathrm{m}}\right)$, and $\boldsymbol{c}=3 \boldsymbol{c}_{\mathrm{m}}+\boldsymbol{a}_{\mathrm{m}}$. The cell parameters suggest the trigonal symmetry. The new atomic coordinates that are obtained by the same basis change followed by a translation of ( $-1 / 3,-1 / 6,-1 / 6$ ) show essentially the trigonal symmetry. The deviations of the atomic coordinates from the average structure having the perfect threefold symmetry were less than 1.2 times of the respective standard deviations. Addition of the threefold axis to the space group $C 2 / c$ gives the space group $R \overline{3} c$. The new atomic coordinates of $\mathrm{MoP}_{3}-$ $\mathrm{SiO}_{11}$ are very close to those of $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$, and the two compounds are isotypic. The cell dimensions of $\mathrm{MoP}_{3} \mathrm{SiO}_{11}$ are slightly larger than those of $\mathrm{RuP}_{3} \mathrm{SiO}_{11}$, which is consistent with the larger ionic radius of molybdenum.

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[^0]:    ${ }^{a}$ Crystal 1 was obtained from the $\mathrm{Ru}-\mathrm{P}-\mathrm{Si}-\mathrm{O}$ system and crystal 2 was obtained from the $\mathrm{Ru}-\mathrm{Nb}-\mathrm{P}-\mathrm{Si}-\mathrm{O}$ system.
    ${ }^{b}$ The cell constant refinement is constrained in the trigonal system.
    ${ }^{c} R=\sum\left(\left\|F_{\mathrm{o}}|-| F_{\mathrm{c}}\right\|\right) / \sum\left|F_{\mathrm{o}}\right|, R_{w}=\left[\sum w\left(\left|F_{\mathrm{o}}\right|-\left|F_{\mathrm{c}}\right|\right)^{2} / \Sigma w F_{\mathrm{o}}^{2}\right]^{1 / 2}(w=$ $\left.1 / \sigma\left(F_{\mathrm{o}}\right)^{2}\right)$.
    ${ }^{d} S=\left[w\left(\left|F_{\mathrm{o}}\right|-\left|F_{\mathrm{c}}\right|\right)^{2} /\left(N_{\text {observns }}-N_{\text {parameters }}\right)\right]^{1 / 2}$.
    ${ }^{e}$ The highest residual electrons of the final difference Fourier map.

[^1]:    ${ }^{a} U_{i j}$ multiplied by 100.

